

Baimei Tan

List of Publications by Year in descending order

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35
papers

425
citations

687363

13
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docs citations

35
times ranked

208
citing authors

#	ARTICLE	IF	CITATIONS
1	Unraveling the Mechanism of Removing NA Contamination by TMAH-Based Cleaning Solution During Post Co-CMP Cleaning. ECS Journal of Solid State Science and Technology, 2022, 11, 034005.	1.8	1
2	Effect of Corrosion Inhibitor BTA on Silica Particles and their Adsorption on Copper Surface in Copper Interconnection CMP. ECS Journal of Solid State Science and Technology, 2022, 11, 044002.	1.8	8
3	Composite complex agent based on organic amine alkali for BTA removal in post CMP cleaning of copper interconnection. Journal of Electroanalytical Chemistry, 2022, 910, 116187.	3.8	7
4	Corrosion inhibitors for Cu chemical mechanical planarization (CMP)., 2022, , 155-170.		0
5	The effect of structural properties of benzo derivative on the inhibition performance for copper corrosion in alkaline medium: Experimental and theoretical investigations. Colloids and Surfaces A: Physicochemical and Engineering Aspects, 2022, 649, 129531.	4.7	15
6	Synergistic effect of LABSA/JFCE combined surfactant system on the removal of particles on copper wafer surface. Materials Chemistry and Physics, 2021, 257, 123841.	4.0	12
7	Experimental validation and molecular dynamics simulation of removal of PO residue on Co surface by alkaline cleaning solution with different functional groups. Colloids and Surfaces A: Physicochemical and Engineering Aspects, 2021, 610, 125932.	4.7	19
8	Toward Understanding the Adsorption And Inhibition Mechanism of Cu-MBTA Passivation Film on Copper Surface: A Combined Experimental and DFT Investigation. Electronic Materials Letters, 2021, 17, 109-118.	2.2	18
9	Adsorption Mechanism of Potassium Oleate on Cobalt Surface Based on Cobalt Interconnection CMP: A Combined Experimental and DFT Investigation. ECS Journal of Solid State Science and Technology, 2021, 10, 024003.	1.8	11
10	Removal of Nanoceria Abrasive Particles by Using Diluted SC1 and Non-Ionic Surfactant. ECS Journal of Solid State Science and Technology, 2021, 10, 034010.	1.8	5
11	Effect of EDTA-based alkaline cleaning solution on TAZ removal in post CMP cleaning of copper interconnection. Materials Research Bulletin, 2021, 137, 111202.	5.2	10
12	Effect of Intermolecular Interaction of Compound Surfactant on Particle Removal in Post-Cu CMP Cleaning. ECS Journal of Solid State Science and Technology, 2021, 10, 064007.	1.8	5
13	Multidimensional insights into the corrosion inhibition of potassium oleate on Cu in alkaline medium: A combined Experimental and theoretical investigation. Materials Science and Engineering B: Solid-State Materials for Advanced Technology, 2021, 272, 115330.	3.5	15
14	Influence of diamond wire saw slicing parameters on (010) lattice plane beta-gallium oxide single crystal wafer. Materials Science in Semiconductor Processing, 2021, 133, 105939.	4.0	4
15	Theoretical and electrochemical analysis on inhibition effects of benzotriazole derivatives (un- and Tj ETQq1 1 0.784314 rgBT ₁₆ /Overlock	3.6	16
16	Unraveling the surface behavior of amino acids on Cu wiring in chemical mechanical polishing of barrier layers: A combination of experiments and ReaxFF MD. Journal of Molecular Liquids, 2021, 341, 117307.	4.9	10
17	Effect of ethylenediamine on CMP performance of ruthenium in H ₂ O ₂ -based slurries. RSC Advances, 2021, 12, 228-240.	3.6	6
18	Effect of arginine-based cleaning solution on BTA residue removal after Cu-CMP. Colloids and Surfaces A: Physicochemical and Engineering Aspects, 2020, 586, 124286.	4.7	36

#	ARTICLE	IF	CITATIONS
19	Corrosion control of copper wiring by barrier CMP slurry containing azole inhibitor: Combination of simulation and experiment. <i>Colloids and Surfaces A: Physicochemical and Engineering Aspects</i> , 2020, 599, 124872.	4.7	44
20	Theoretical and electrochemical analysis on inhibition effect of benzotriazole and 1,2,4-triazole on cobalt surface. <i>Colloids and Surfaces A: Physicochemical and Engineering Aspects</i> , 2020, 591, 124516.	4.7	28
21	Synergistic effect of composite complex agent on BTA removal in post CMP cleaning of copper interconnection. <i>Materials Chemistry and Physics</i> , 2020, 252, 123230.	4.0	27
22	Synergetic Effect of 5-Methyl-1H-Benzotriazole and Sodium Dodecyl Benzene Sulfonate on CMP Performance of Ruthenium Barrier Layer in KIO ₄ -Based Slurry. <i>ECS Journal of Solid State Science and Technology</i> , 2020, 9, 104005.	1.8	6
23	Study on Different Surfactants for Post CMP Cleaning of Novel Barrier. , 2019, , .		1
24	Study on Infrared Spectrum Detection and Analysis of BTA Residual after Copper CMP. , 2019, , .		0
25	Effects of Novel Inhibitor on Galvanic Corrosion of Copper and Cobalt and Particle Removal. <i>ECS Journal of Solid State Science and Technology</i> , 2019, 8, P545-P552.	1.8	11
26	Study on the Adsorption and Inhibition Mechanism of 1,2,4-Triazole on Copper Surface in Copper Interconnection CMP. <i>ECS Journal of Solid State Science and Technology</i> , 2019, 8, P313-P318.	1.8	15
27	A study of FTIR and XPS analysis of alkaline-based cleaning agent for removing Cu-BTA residue on Cu wafer. <i>Surface and Interface Analysis</i> , 2019, 51, 566-575.	1.8	28
28	Optimization of cleaning process parameters to remove abrasive particles in post-Cu CMP cleaning. <i>Journal of Semiconductors</i> , 2018, 39, 126002.	3.7	4
29	Effect of organic amine alkali and inorganic alkali on benzotriazole removal during post Cu-CMP cleaning. <i>Journal of Semiconductors</i> , 2018, 39, 126003.	3.7	7
30	Application of surfactant for facilitating benzotriazole removal and inhibiting copper corrosion during post-CMP cleaning. <i>Microelectronic Engineering</i> , 2018, 202, 1-8.	2.4	24
31	Role of Penetrating Agent on Colloidal Silica Particle Removal during Post Cu CMP Cleaning. <i>ECS Journal of Solid State Science and Technology</i> , 2018, 7, P380-P384.	1.8	9
32	Thermal Stability Study of GaP/High- κ Dielectrics Interfaces. <i>Advanced Materials Interfaces</i> , 2017, 4, 1700609.	3.7	5
33	A novel cleaner for colloidal silica abrasive removal in post-Cu CMP cleaning. <i>Journal of Semiconductors</i> , 2015, 36, 106002.	3.7	5
34	Non-ionic surfactant on particles removal in post-CMP cleaning. <i>Journal of Semiconductors</i> , 2015, 36, 026002.	3.7	13
35	Eco-friendly Corrosion Inhibitors for Multilevel Metal Interconnects of Integrated Circuits. <i>ACS Symposium Series</i> , 0, , 149-165.	0.5	0